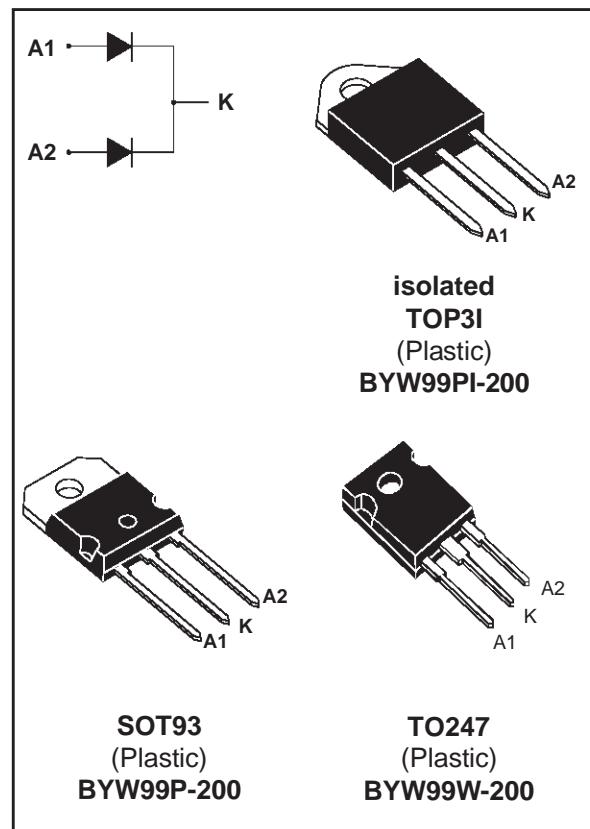


HIGH EFFICIENCY FAST RECOVERY RECTIFIER DIODES

FEATURES

- SUITED FOR SMPS
- VERY LOW FORWARD LOSSES
- NEGLIGIBLE SWITCHING LOSSES
- HIGH SURGE CURRENT CAPABILITY
- HIGH AVALANCHE ENERGY CAPABILITY
- INSULATED VERSION TOP3I :
Insulating voltage = 2500 V DC
Capacitance = 12 pF



DESCRIPTION

Dual center tap rectifier suited for switchmode power supply and high frequency DC to DC converters.

Packaged in SOT93, TOP3I or TO247 this device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter				Value	Unit
I _{F(RMS)}	RMS forward current			Per diode	35	A
I _{F(AV)}	Average forward current $\delta = 0.5$	SOT93 / TO247	T _c =120°C	Per diode	15	A
		TOP3I	T _c =115°C	Per diode	15	
I _{FSM}	Surge non repetitive forward current	tp=10ms sinusoidal	Per diode	200		A
T _{stg} T _j	Storage and junction temperature range			- 40 to + 150	- 40 to + 150	°C °C
Symbol	Parameter				Value	Unit
V _{RRM}	Repetitive peak reverse voltage				200	V

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THERMAL RESISTANCES

Symbol	Parameter			Value	Unit
R _{th} (j-c)	Junction to case	SOT93 / TO247	Per diode	1.8	°C/W
			Total	1.0	
	TOP3I	TOP3I	Per diode	2.0	
			Total	1.25	
R _{th} (c)	Coupling	SOT93 / TO247		0.2	°C/W
		TOP3I		0.5	

When the diodes 1 and 2 are used simultaneously :

$$T_j - T_c (\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)} (\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}$$

STATIC ELECTRICAL CHARACTERISTICS (Per diode)

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
I _R *	T _j = 25°C	V _R = V _{RRM}			20	μA
	T _j = 100°C				1.5	mA
V _F **	T _j = 125°C	I _F = 12 A			0.85	V
	T _j = 125°C	I _F = 25 A			1.05	
	T _j = 25°C	I _F = 25 A			1.15	

Pulse test : * tp = 5 ms, δ < 2 %

** tp = 380 μs, δ < 2 %

To evaluate the conduction losses use the following equation :

$$P = 0.65 \times I_F(AV) + 0.016 \times I_F^2(\text{RMS})$$

RECOVERY CHARACTERISTICS

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
trr	T _j = 25°C	I _F = 0.5A	I _{rr} = 0.25A		25	ns
		I _F = 1A	dI _F /dt = -50A/μs		40	
tfr	T _j = 25°C	I _F = 1A	tr = 10 ns	15		ns
V _{FP}	T _j = 25°C	I _F = 1A	tr = 10 ns	2		V

Fig.1 : Average forward power dissipation versus average forward current.

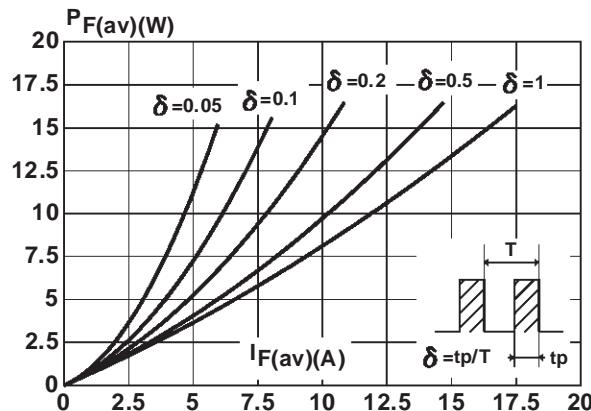


Fig.3 : Forward voltage drop versus forward current (maximum values).

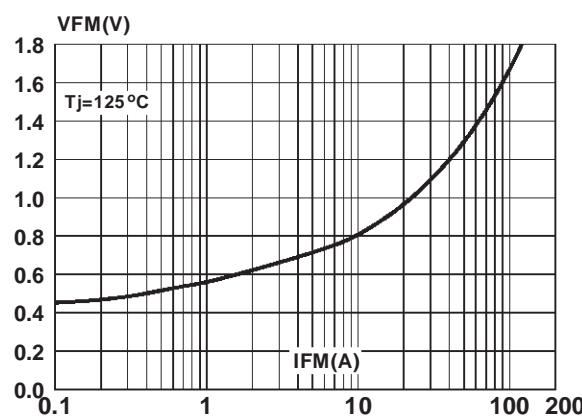


Fig.5 : Non repetitive surge peak forward current versus overload duration.
(SOT93, TO247)

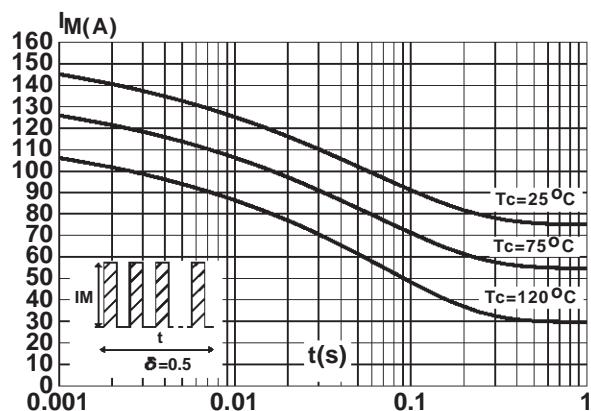


Fig.2 : Peak current versus form factor.

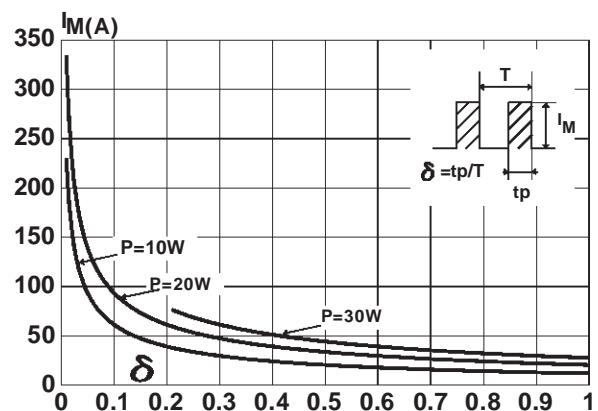


Fig.4 : Relative variation of thermal impedance junction to case versus pulse duration.

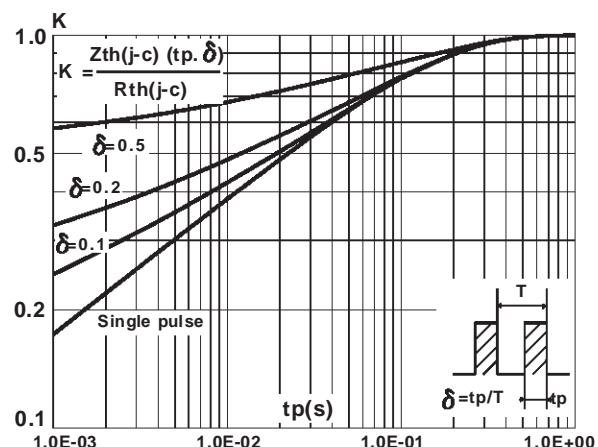
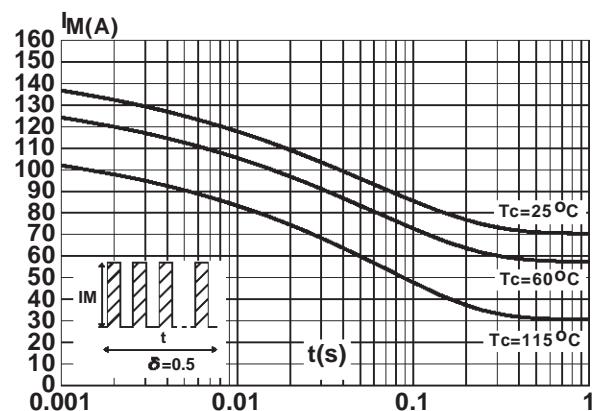


Fig.6 : Non repetitive surge peak forward current versus overload duration.
(TOP3I)



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Fig.7 : Average current versus ambient temperature.
 $(\delta = 0.5)$ (SOT93, TO247)

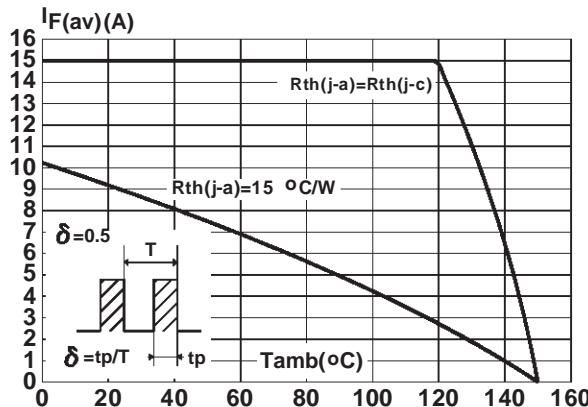


Fig.9 : Junction capacitance versus reverse voltage applied (Typical values).

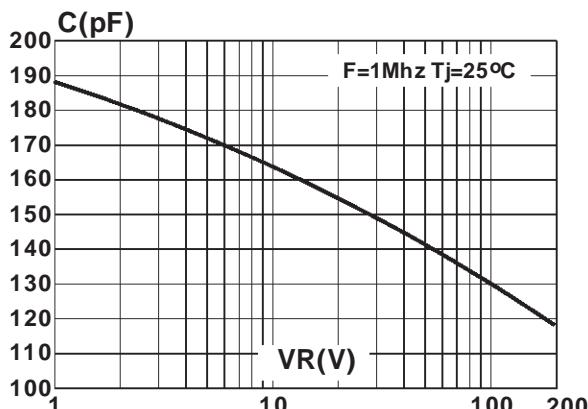


Fig.11 : Peak reverse current versus dIF/dt.

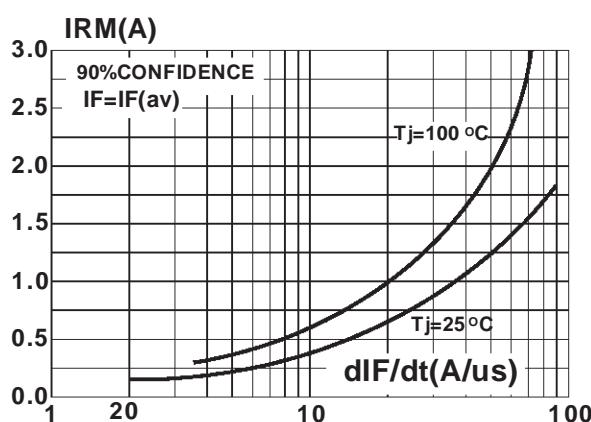


Fig.8 : Average current versus ambient temperature.
 $(\delta = 0.5)$ (TOP3I)

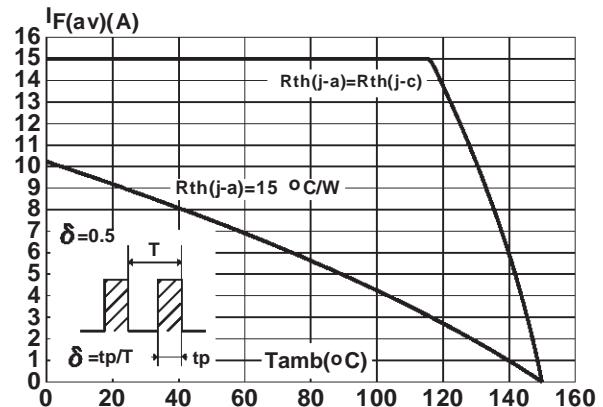


Fig.10: Recovery charges versus dI_F/dt.

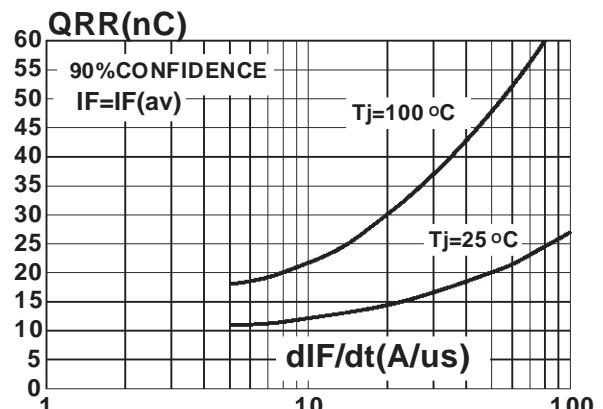
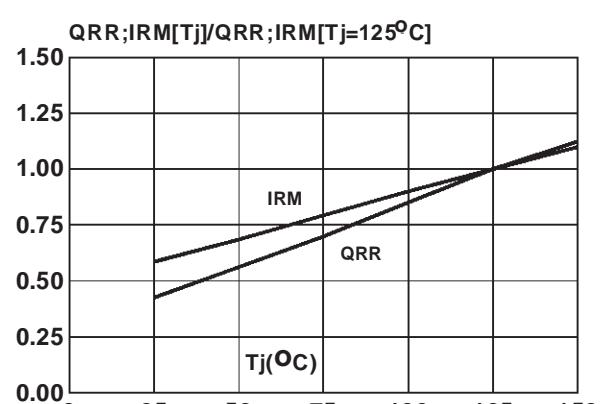
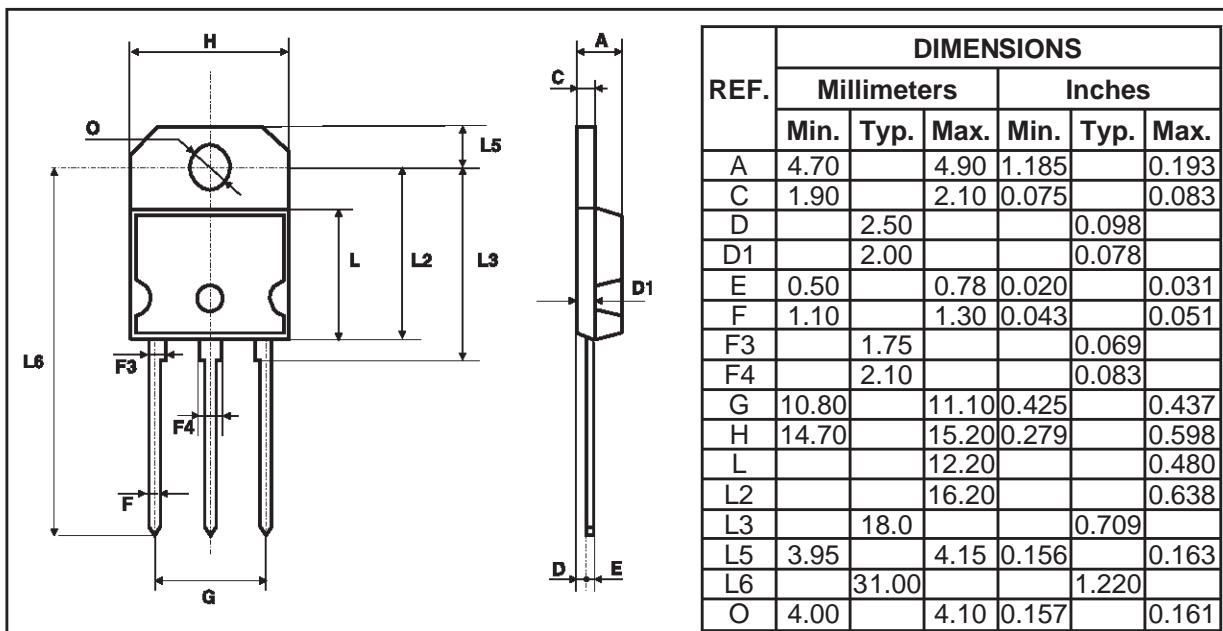
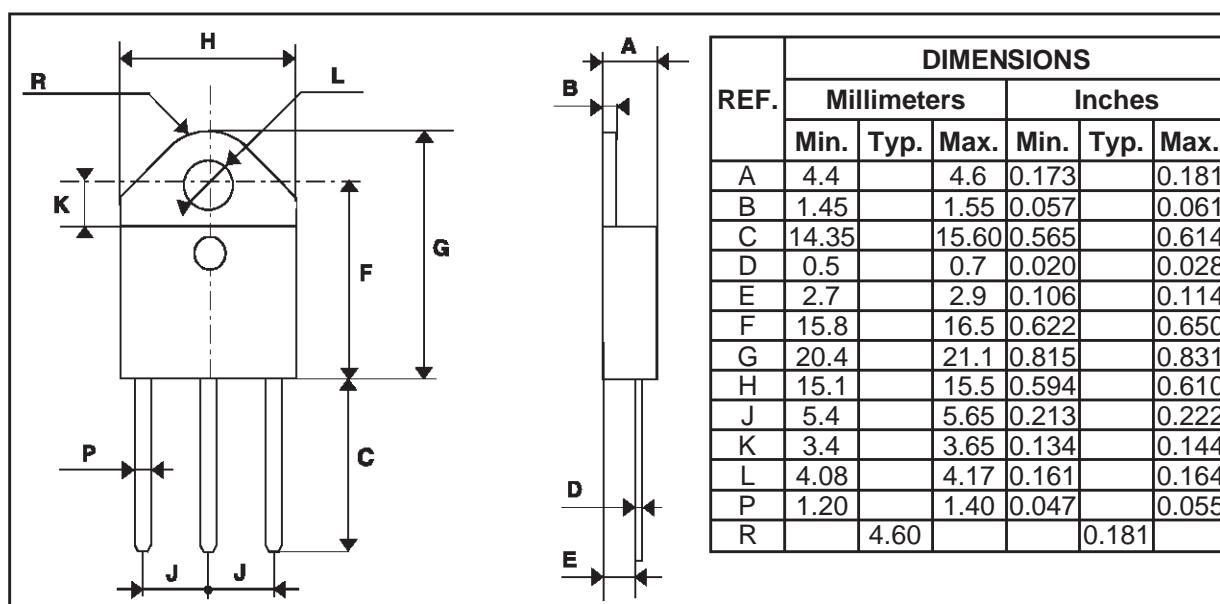


Fig.12 : Dynamic parameters versus junction temperature.



PACKAGE MECHANICAL DATA
SOT93


- **Marking** : Type number
- **Cooling method** : C
- **Weight** : 5.3 g
- **Recommended torque value** : 0.8m.N
- **Maximum torque value** : 1.0m.N

PACKAGE MECHANICAL DATA
TOP3I (isolated)


- **Marking** : Type number
- **Cooling method** : C
- **Weight** : 4.7 g
- **Recommended torque value** : 0.8m.N
- **Maximum torque value** : 1.0m.N

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PACKAGE MECHANICAL DATA TO247

REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.85		5.15	0.191		0.203
D	2.20		2.60	0.086		0.102
E	0.40		0.80	0.015		0.031
F	1.00		1.40	0.039		0.055
F1		3.00			0.118	
F2		2.00			0.078	
F3	2.00		2.40	0.078		0.094
F4	3.00		3.40	0.118		0.133
G		10.90			0.429	
H	15.45		15.75	0.608		0.620
L	19.85		20.15	0.781		0.793
L1	3.70		4.30	0.145		0.169
L2		18.50			0.728	
L3	14.20		14.80	0.559		0.582
L4		34.60			1.362	
L5		5.50			0.216	
M	2.00		3.00	0.078		0.118
V		5°			5°	
V2		60°			60°	
Dia.	3.55		3.65	0.139		0.143

- **Marking :** Type number
- **Cooling method :** C
- **Weight :** 4.4 g
- **Recommended torque value :** 0.8m.N
- **Maximum torque value :** 1.0m.N

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